

Bidirectional TVS Diodes

DESCRIPTION

The GSDxxC Series is designed for applications overvoltage reauirina transient protection capability. They are intended for use in voltage and ESD sensitive equipment such as computers, business machines, communication printers, systems, medical equipment and other applications. These devices are ideal for situations where board space is at a premium.

This series has been specifically designed to protect sensitive components which are connected to power, data and transmission lines from overvoltage caused by ESD(electrostatic discharge), CDE (Cable Discharge Events),and EFT (electrical fast transients).

ORDERING INFORMATION

- ♦ Device: GSDxxC
- ♦Package: SOD-323
- ♦Material: Halogen free and RoHS compliant
- ♦Packing: Tape & Reel
- ♦Quantity per reel: 3,000pcs

FEATURES

- ◇I IEC61000-4-2 (ESD) ±30kV (Contact) ±30kV (Air)
- ♦IEC61000-4-4 (EFT) 40A (5/50ηs)
- Protects one I/O line (bidirectional)
- ♦Low clamping voltage
- ♦Working voltages:

3V,5V,8V,12V,15V,18V,20V,24V,36V

♦Low leakage current

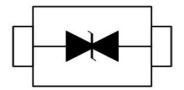
MACHANICAL DATA

- ♦ SOD-323 package
- ♦ Flammability Rating: UL 94V-0
- ♦Packaging: Tape and Reel
- ♦High temperature soldering guaranteed: 260℃/10s
- ♦Reel size: 7 inch
- ♦MSL 1

APPLICATIONS

- ♦ Cell Phone Handsets and Accessories
- Microprocessor based equipment
- ♦ Personal Digital Assistants (PDA's)
- ♦Notebooks, Desktops, and Servers
- ♦Portable Instrumentation
- ♦Networking and Telecom
- ♦ Serial and Parallel Ports.
- ♦Peripherals

PIN CONFIGURATION



PACKAGE OUTLINE





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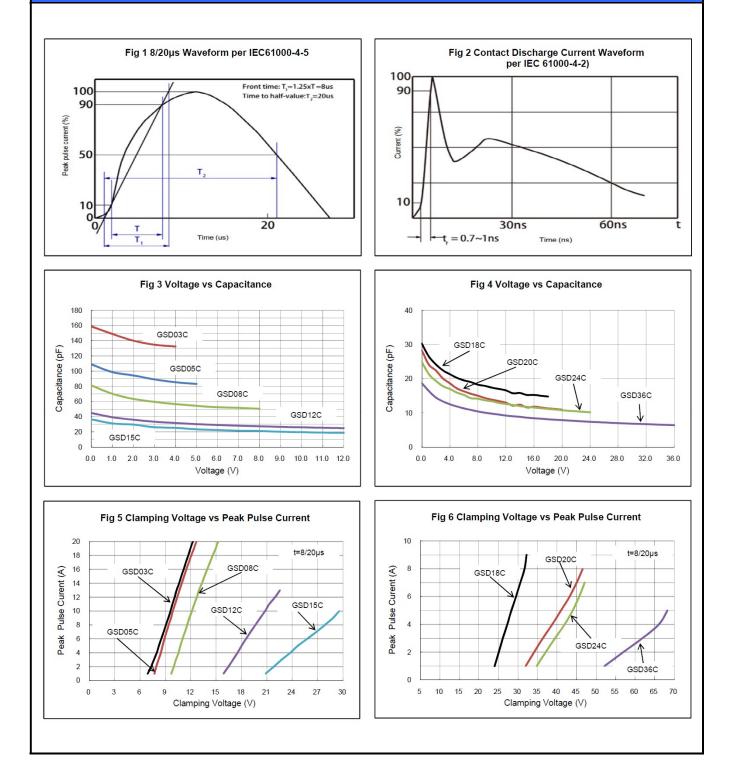
ABSOL	ABSOLUTE MAXIMUM RATING						
Symbol	Parameter	Value	Units				
VESD	ESD per IEC 61000-4-2 (Contact) ESD per IEC 61000-4-2 (Air)	±30 ±30	kV				
P _{PP}	Peak Pulse Power (8/20µs)	350	W				
T _{OPT}	Operating Temperature	-55/+150	°C				
T _{STG}	Storage Temperature	-55/+150	°C				
T∟	Lead Soldering Temperature	260 (10 sec.)	°C				

ELECTRICA	LECTRICAL CHARACTERISTICS (Tamb=25°C)								
PART NUMBER	DEVICE MARKING	V _{RWM} (V) (max.)	V _B (V) (min.)	I⊤ (mA)	V _C @1A (V) (max.)	۷ (/ (max.)	/c /) (@A)	Ι _R (μΑ) (max.)	C⊤ (pF) (max.)
GSD03C	2A	3.3	4.0	1	7.5	16.0	20	40	450
GSD05C	2B	5.0	6.0	1	9.8	18.0	17	10	200
GSD08C	2C	8.0	8.5	1	13.4	24.0	15	2	120
GSD12C	2D	12.0	13.3	1	19.0	32.0	11	1	75
GSD15C	2J	15.0	16.7	1	24.0	38.0	10	1	68
GSD18C	2K	18.0	20.0	1	29.0	45.0	9	1	57
GSD20C	2L	20.0	22.3	1	35.0	50.0	8	1	52
GSD24C	2H	24.0	26.7	1	43.0	52.0	7	1	50
GSD36C	2N	36.0	40.0	1	60.0	75.0	4.5	1	35



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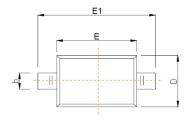
ELECTRICAL CHARACTERISTICS CURVE

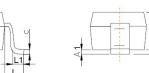




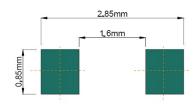
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SOD-323 PACKAGE OUTLINE DIMENSIONS





Cumpleal	Dimensions In Millimeters				
Symbol –	Min	Max			
A		1.00			
A1	0.000	0.100			
A2	0.800	0.900			
b	0.250	0.350			
С	0.080	0.150			
D	1.200	1.400			
E	1.600	1.800			
E1	2.500	2.700			
е	1.800	2.040			
L	0.475 REF				
L1	0.250	0.400			
θ	0°	8°			



A2

Recommended Pad outline